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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/596,380	06/12/2006	Steven C. Deane	GB030221	5921
24737 7590 08/08/2008 PHILIPS INTELLECTUAL PROPERTY & STANDARDS P.O. BOX 3001 PDIA DCI IFE MANOR NIV 10510			EXAMINER	
			NHU, DAVID	
BRIARCLIFF MANOR, NY 10510		ART UNIT	PAPER NUMBER	
			2895	
			MAIL DATE	DELIVERY MODE
			08/08/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)			
Office Action Comments	10/596,380	DEANE, STEVEN C.			
Office Action Summary	Examiner	Art Unit			
	DAVID NHU	2895			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 2 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).					
Status					
1)⊠ Responsive to communication(s) filed on <u>08 Ju</u>	dv 2008.				
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closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims					
4)⊠ Claim(s) <u>1-11</u> is/are pending in the application.					
4a) Of the above claim(s) <u>1-4 and 6</u> is/are withdrawn from consideration.					
5) Claim(s) is/are allowed.					
6) Claim(s) is/are rejected.					
7)⊠ Claim(s) <u>5 and 7-11</u> is/are objected to.					
8) Claim(s) are subject to restriction and/or	election requirement.				
Application Papers					
·· _ ·					
9) The specification is objected to by the Examiner. 10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.					
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).					
a)⊠ All b)□ Some * c)□ None of:					
	1. Certified copies of the priority documents have been received.				
2. Certified copies of the priority documents have been received in Application No					
3. Copies of the certified copies of the priority documents have been received in this National Stage					
application from the International Bureau (PCT Rule 17.2(a)).					
* See the attached detailed Office action for a list of the certified copies not received.					
Attachment(s)					
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413)					
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Date				
3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 7/8/08. 5) Notice of Informal Patent Application 6) Other:					
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Art Unit: 2818

DETAIL ACTIONS

Claims

1. Claim 5, "a vertical n-i-p stack is used by using a doped region of the polysilicon thin film transistor for n-type region" should be —a vertical n-i-p stack is used by using a doped region of a polysilicon thin film transistor (TFT) for the n-type **doped** region—Claim 7, "wherein a distance between the doped regions is substantially equal to a gap between adjacent thin film transistors" should be --wherein a distance between **the p-type** and **n-type** doped regions is substantially equal to a gap between adjacent thin film transistors

(TFTs)-Claim 9, to control the conductivity" should be -to control **a** conductivity--

Conclusion

2. Prosecution on the merits is closed in accordance with the practice under *Ex parte*, *Quayle*, 1935 C.D. 11, 453 O.G. 213.

A shortened statutory period for reply to this action is set to expire **TWO MONTHS** from the mailing date of this letter.

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Nhu, (751)272-1792.

The examiner can normally be reached on Monday-Friday 7:00 am-5:00pm...

The fax phone number for the organization where this application or proceeding is assigned is (571)273-8300.

/David Nhu/ 7/20/2008 DN

Primary Examiner, Art Unit 2895